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# Local Distortions in Nanostructured Ferroelectric Ceramics through Strain Tuning

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Ferroelectric materials are highly sensitive to grain size reduction because strain and ferroelectric polarization have a direct connection. Using 15 nm (Ba,Sr)TiO<sub>3</sub> particles obtained by advanced supercritical synthesis and their densification by high-pressure spark plasma sintering under air, reproducible and dense nanostructured ceramics are achieved. Taking advantage of the high pressure (up to 600 MPa) applied during the sintering step, the internal stress generated at the grain scale can be monitored to compensate for the particle surface stress due to size effect. Both the local dynamics observed by Raman scattering and the overall dielectric behavior consistently indicate a recovery of the ferroelectric properties as the sintering pressure is increased. This unique behavior shows that low-temperature and high-pressure processing enables designing nanostructured functional ceramics exhibiting original properties.

## 1. Introduction

Several functional oxides exhibit properties highly sensitive to particle size. The stabilization of phases in polymorphic materials such as ZrO<sub>2</sub>, Al<sub>2</sub>O<sub>3</sub>, and TiO<sub>2</sub> is modified in nanopowders and unusual phases can be retained at the nanoscale. [1-5] The effect of strain and surface energies on the stabilization of metastable polymorphs has been evidenced. Besides, because of the large coupling between spontaneous lattice strain and polarization, ferroelectric properties are dependent on grain size in ferroelectric ceramics. Below a critical grain size, which depends strongly on the processing conditions, a decrease of the tetragonal distortion and thus a stabilization of the cubic phase are observed. [6-11] Zhao et al. have provided new insights in size effect through a systematic investigation of crystal structure, phase transitions, and permittivity, performed on highly densified nanocrystalline BaTiO<sub>3</sub> ceramics (50–1200 nm) obtained using spark plasma sintering (SPS). [12] An additional contribution when referring to nanocrystals lies in the presence of hydroxyl defects, which can drastically affect the surface energy. [6,11,13–15] As a consequence, controlling composition, defects, particle size, and crystallinity is mandatory to master the dielectric properties. This represents a major issue to face the drastic expectations in the field of ferroelectric ceramics for electronic applications. However, producing well-crystallized sub-50 nm grains of narrow size distribution over a whole solid solution and keeping such fine grain size within the final ceramic is still challenging. Although the grain size effect in BaTiO<sub>3</sub> has been largely reported in literature, only few studies are devoted to nanostructured barium strontium titanate ceramics (Ba<sub>1-x</sub>Sr<sub>x</sub>TiO<sub>3</sub> δ x δ 1). [16-19] Both the synthesis route

used to produce the initial particles and the shaping process are major steps to reach a reliable buildup of the nanostructured materials. We emphasize here the advantages of combining supercritical fluid synthesis and spark plasma sintering to produce functional nanostructured ceramics. These fast processes allow an accurate control of size, chemistry, and crystallinity leading to an appropriate control of the properties at the nanoscale. The supercritical fluid method offers continuous, scalable, fast, and facile routes toward well-crystallized tailormade oxide nanoparticles. The accurate control of size through the process operating parameters can give access to the critical size of nanostructures as exemplified by crystalline  $ZrO_2$ . [20] A critical particle size of 5–6 nm for monoclinic  $ZrO_2$  is obtained and either monoclinic or tetragonal zirconia phases can be obtained in the continuous supercritical reactor. Beyond size effects, this versatile technique also allows tuning materials crystallinity; this was demonstrated with the case of alumina by a simple modification of the fluid nature. Amorphous or boehmite alumina can be successfully obtained using  $CO_2$ /ethanol or  $H_2O$ /ethanol, respectively. A significant decrease of the  $\alpha$ - $Al_2O_3$   $\rightarrow$   $\gamma$ - $Al_2O_3$  transition temperature is obtained with the amorphous alumina resulting in a lower densification temperature. [21] Amorphous but also highly crystalline nanostructures can be designed using the supercritical fluid technology with the synthesis of exciton luminescent ZnO nanoparticles. [22] Furthermore, the control of the chemistry in supercritical fluids offers the possibility to master materials composition and the case of  $BaTiO_3$  based nanoparticles is a good example. [23] Nanopowders of the whole solid solution  $Ba_{1-x}Sr_xTiO_3$  ( $0 \leq x \leq 1$ ) are now easily accessible. [24,25] Besides, among the consolidation techniques, SPS is well recognized as a very efficient tool to yield functional ceramics with controlled microstructures (i.e., low level of porosity and tailored grain size). [26,27] It has been clearly evidenced in literature that an applied pressure during sintering drastically enhances the densification via sliding, rearrangement, or plastic deformation of the particles. This effect combined with high heating rates achieved in field-assisted sintering allows obtaining dense nanostructured ceramics. To illustrate this purpose, one can refer to the work of Anselmi-Tamburini et al. in which they developed a tool allowing high pressure up to GPa. [28] They have been able to obtain from a cubic  $ZrO_2$  nanopowder (15 nm average grain size) dense ceramics (relative density,  $D_r = 95\%$ ) without grain growth compared to the initial powder.

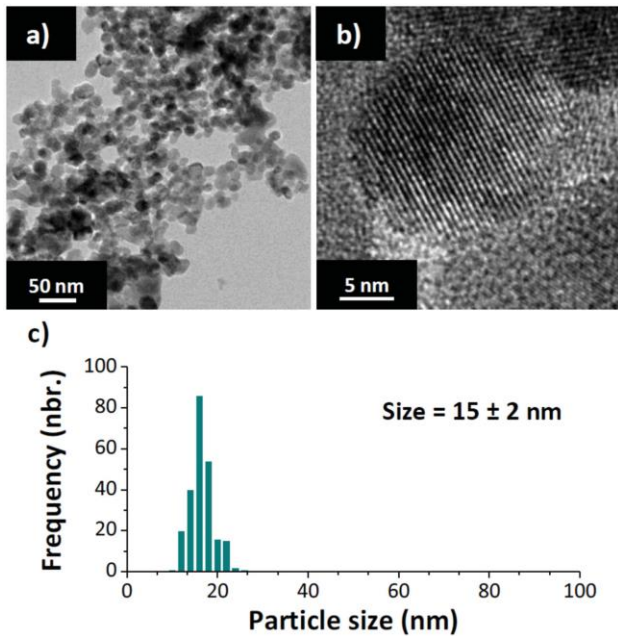
We illustrate here that the association of high-pressure SPS under air with the continuous and controlled design of oxide particles by supercritical fluids is a fast and flexible approach toward the investigation of nanostructured ceramics made of barium strontium titanate ( $Ba_{0.6}Sr_{0.4}TiO_3$  or BST64) with grain size below 20 nm. SPS sintering under air of nanostructured ceramics applying uniaxial pressures of several hundred of MPa was not yet reported in literature in the field of ferroelectric materials. The previous investigations related to size effect and based on spark plasma sintering refer to powders with grain size larger than 50 nm and applied pressure in the range 50–100 MPa. We will emphasize here the particle size effect and the role of the external pressure applied during sintering on the short range order structure, which strongly impact the macroscopic properties.

## 2. Results

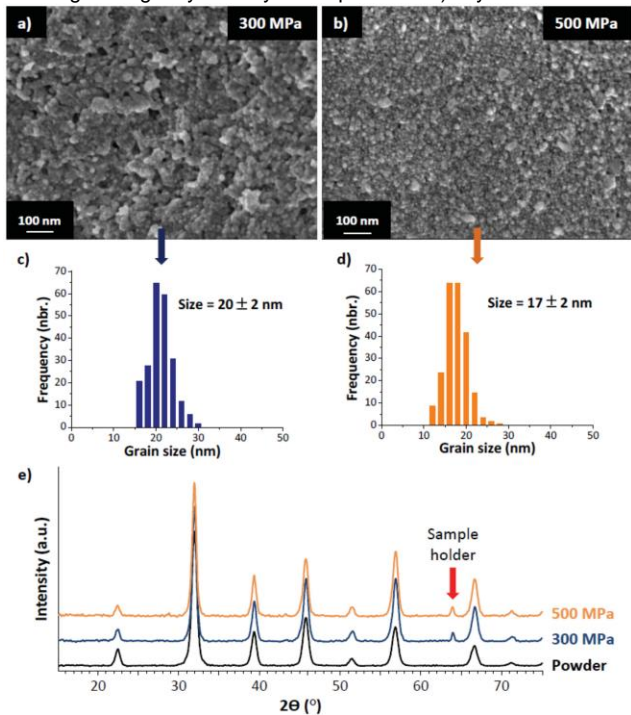
### 2.1. SPS Sintering and Microstructural Characterizations

Well-crystallized BST64 nanoparticles with an average size of

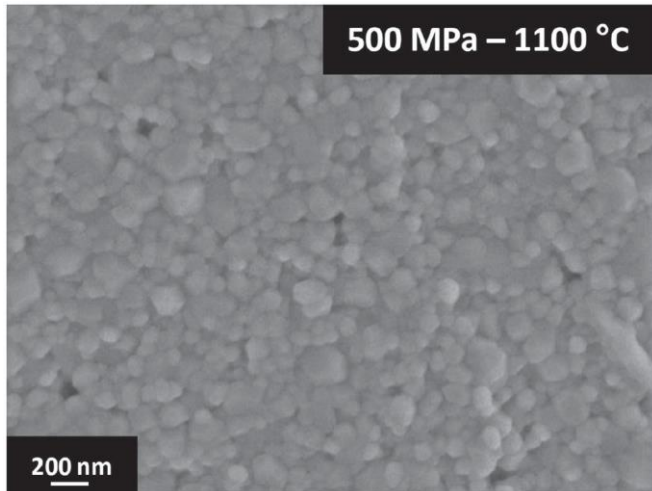
15 nm and a very narrow particle size distribution ( $\sigma$  2 nm) were directly obtained after synthesis ( **Figure 1** ). No additional calcination step was required prior sintering neither to improve the crystallinity nor to release undesirable barium carbonates. In order to fulfill the expectations in terms of grain size control within the final ceramic, the SPS temperature was maintained as low as 750 °C and the pressure was increased from 300 up to 600 MPa in order to improve the densification. Increasing the compressive stress applied during SPS up to several hundreds of MPa favors the elimination of agglomerates, enhances the densification mechanisms, and activates mechanisms such as plastic deformation or grain boundary sliding at low temperature. As a result, homogeneous subsequent densification without grain growth is promoted. Air atmosphere was selected to limit detrimental reduction of titanium arising when SPS is performed under low oxygen partial pressure atmosphere. [ 29,30] Increasing the pressure from 300 up to 400 MPa raised density from 86% to 91% and a further pressure increase up to 600 MPa did not lead to significant improvement in density. High resolution scanning electron microscopy (HRSEM) analysis shows unambiguously that, whatever the applied pressure, the average grain size after SPS is close to 20 nm, as shown for 300 and 500 MPa in **Figure 2** a–d, respectively. The postannealing at 700 °C performed to release residual stress arising from SPS process allows reaching a density value as high as 93% (pressure 400–600 MPa) without an increase of the average grain size which remains lower than 20 nm. No extra phase was observed on the X-ray diffraction (XRD) pattern after SPS sintering. The width of the peaks remained similar between the raw powder (before SPS), the ceramic and the ceramic annealed at 700 °C, confirming the absence of grain growth whatever the applied pressure. No splitting of the pseudo cubic (200) into tetragonal (200) and (002) reflections appeared after sintering suggesting an average cubic structure in both the initial powder and the SPS ceramics (Figure 2 e). SPS ceramics were then annealed at 1100 °C in order to induce grain coarsening and then to probe the impact of grain growth on both structural and dielectric features. After the thermal treatment and whatever the pressure initially applied during SPS, the grain size within the ceramics reaches 100 nm as shown by HRSEM ( **Figure 3** ).



**Figure 1.** a) Transmission electron microscopy (TEM) image of  $\text{Ba}_{0.6}\text{Sr}_{0.4}\text{TiO}_3$  nanoparticles synthesized by supercritical fluids and b) high resolution transmission electron microscopy (HRTEM) image showing the high crystallinity of the particles. c) Crystal size distribution.



**Figure 2.** a,b) HRSEM images of the fracture surface of the BST ceramics processed by spark plasma sintering at 750 °C under uniaxial pressure of 300 and 500 MPa, respectively; c,d) the corresponding grain size distributions; and e) X-ray diffraction patterns of BST nanopowder and BST ceramics sintered under uniaxial pressures of 300 and 500 MPa.



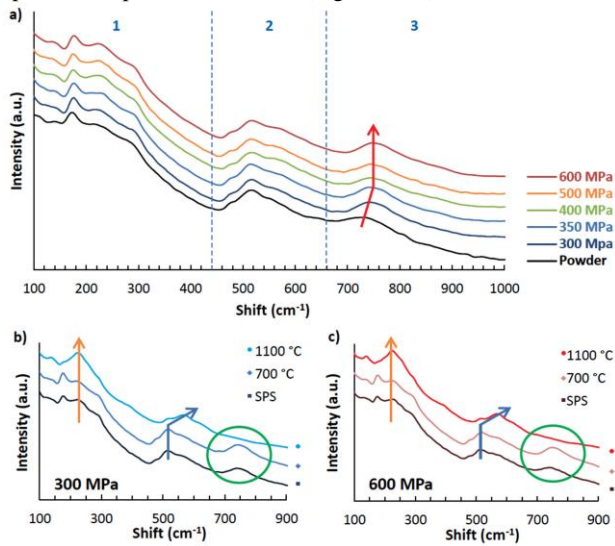
**Figure 3.** HRSEM image of the fracture surface of the BST ceramic processed at 500 MPa after annealing at 1100 °C.

## 2.2. Short Range Structure Investigation by Raman Spectroscopy

As shown in several reports from literature, the local structure in nanosized ferroelectrics does not possess as high symmetry as XRD measurements may suggest (Figure 2 e). [ 6,11,31–33 ] To get better insight into the structure at the unit cell level (i.e., short range) Raman spectroscopy offers the advantage to be accurate either on powder or ceramic and is very sensitive to the local dynamic symmetry with a coherence length lower than 2 nm. The influence of pressure applied during SPS on the local structure will be discussed here considering the evolution of Raman spectra within the relevant frequency range involving oxygen octahedral vibrations. Soft Raman modes related to intrinsic size effect on ferroelectricity occur at frequencies lower than the ones investigated here and thus will not be considered in our discussion. The comparison of spectra between the powder and the ceramics sintered at different pressures highlights three main differences ( **Figure 4 a**):

- The peak close to 180  $\text{cm}^{-1}$  associated to a marked negative dip is observed in the powder but becomes more pronounced in the ceramics. This mode was already reported in literature and is ascribed to a strain-induced orthorhombic phase, which can be locally stabilized at room temperature in a nanosized ferroelectric. [ 6,34 ] Such an increase of the polar character at a very local scale is supported by the intensity increase of the  $A_1(\text{TO})$  peak close to 230  $\text{cm}^{-1}$  which becomes more prominent after the SPS step. The overall broad spectral signature can be associated with an overall pseudo cubic character.
- The only shift observed in the spectra occurs at the 730  $\text{cm}^{-1}$  mode. This mode is attributed to a combination of  $A_1(\text{LO})$  and  $E(\text{LO})$  modes that consist of motions of the Ti and O1 (apical oxygen sites) against the O2 and O3 planar oxygens in the  $\text{TiO}_6$  octahedron. Hence, such a shift is related to an increase of the unit cell distortion (orthorhombic or tetragonal). [ 35 ] The Raman peak at 810  $\text{cm}^{-1}$  related to the presence of structural OH defects and present in the powder is released in the ceramic thus demonstrating the stabilization of the long range tetragonal structure.
- The Raman investigation performed on the ceramics annealed at 1100 °C (grain size close to 100 nm) revealed noticeable changes: the shift of the mode at 500–600  $\text{cm}^{-1}$  and the disappearance of the peak at 180  $\text{cm}^{-1}$ . These features were similarly observed for the ceramics sintered under 300 and 600 MPa.

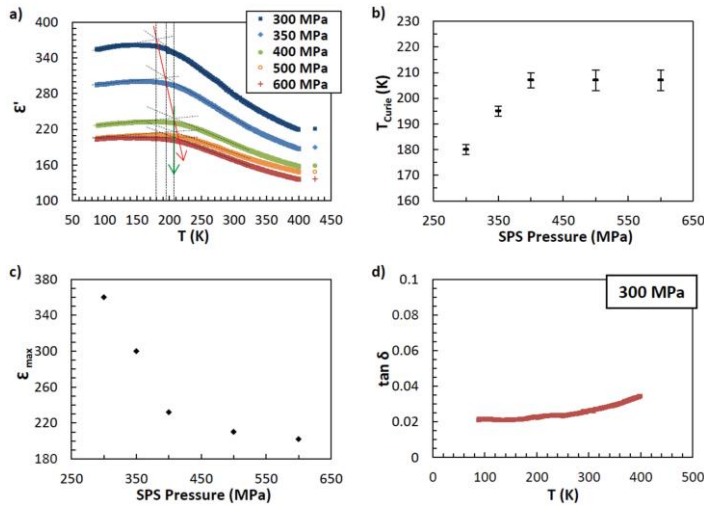
The overall spectral signature resembles the traditional Raman spectrum of pseudo cubic BST (Figure 4 b,c). [ 36 ]



**Figure 4.** Raman spectra of a) BST nanopowder and SPS ceramics processed at different pressures from 300 up to 600 MPa and b,c) ceramics processed by SPS at 300 and 600 MPa, respectively, and annealed at 700 and 1100 °C in each case. Arrows indicate the shift observed in different modes of the spectra.

### 2.3. Dielectric Characterizations

The dielectric measurements performed on the SPS nanostructured ceramics clearly show the existence of a phase transition with a maximum of permittivity as a function of temperature whatever the applied pressure during SPS ( **Figure 5 a** ). The Curie temperature ( $T_c$ ) of the ceramic obtained at 300 MPa is estimated close to 180 K. Increasing pressure during sintering led to two noticeable effects: (i) a decrease of the permittivity (despite of the increase in ceramic density) and (ii) a variation of the Curie temperature associated with a broadening of the transition maximum. Reporting the Curie temperature as a function of the applied pressure during sintering evidences unambiguously an increase of the transition temperature from 180 to 207 K when the pressure increases from 300 to 400 MPa, respectively, and then  $T_c$  remains stable in a second regime from 400 to 600 MPa (Figure 5 b). In parallel, the maximum of permittivity at  $T_c$  can be plotted as a function of the applied pressure (Figure 5 c). Similarly to the  $T_c$  evolution as a function of the pressure, two regimes can be distinguished, the  $\Sigma_{max}$  values decrease for a SPS pressure up to 400 MPa, and then stabilize with a further increase of pressure up to 600 MPa.



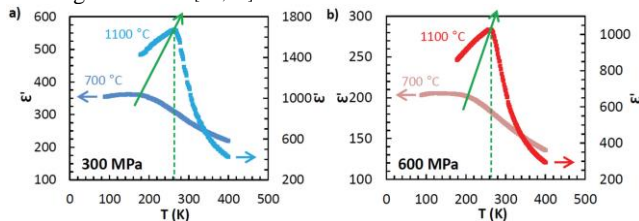
**Figure 5.** a) Permittivity temperature dependence ( $f = 10$  kHz) of ceramics processed at different applied pressures, b) evolution of the Curie temperature as a function of the pressure applied during sintering, c) evolution of the maximum of permittivity as a function of the pressure applied during sintering and d) temperature dependence of the dielectric losses for the ceramic sintered under 300 MPa.

The dielectric losses stabilization in the overall temperature range can be highlighted (Figure 5 d). Such values ranging between 0.02 and 0.04 are quite low considering the high density of grain boundaries and confirm that the macroscopic properties are not mainly dominated by extrinsic contributions such as charged defects at the grain boundaries. This is in good agreement with the low permittivity, which is not artificially raised by such extrinsic contributions.

The grain growth resulting from the annealing of the SPS ceramics led to significant changes on the dielectric properties: an increase of the permittivity, a narrower paraelectric-ferroelectric phase transition and a shift of the  $T_C$  toward a higher and stable value (265 K) whatever the applied SPS pressure (Figure 6).

### 3. Discussion

The first significant result lies in the processing of well-densified nanostructured BST64 ceramics with 20 nm grains. Using both highly crystallized and pure initial BST nano powders and specific SPS conditions (air atmosphere and high pressure) allowed avoiding thermal treatments at high temperature leading to grain growth. Raman investigation revealed an increase of the polar character at a very local scale in the nanostructured ceramic compared to the nanopowder. The ferroelectric transition was evidenced close to 180 K. This result allowed to complete with good agreement the study of Hornebecq et al. reporting the  $T_C$  evolution of  $Ba_{0.6}Sr_{0.4}TiO_3$  particles as a function of their grain size. [16] The permittivity and losses remained low in spite of the high density of grain boundaries, therefore discarding any significant extrinsic contribution of charged defects. [37,38]



**Figure 6.** Permittivity temperature dependences ( $f = 10$  kHz) of ceramics processed by SPS at a) 300 MPa and b) 600 MPa and annealed at 700 and 1100 °C in each case. Arrows indicate the increase of the Curie temperature after annealing at high temperature.



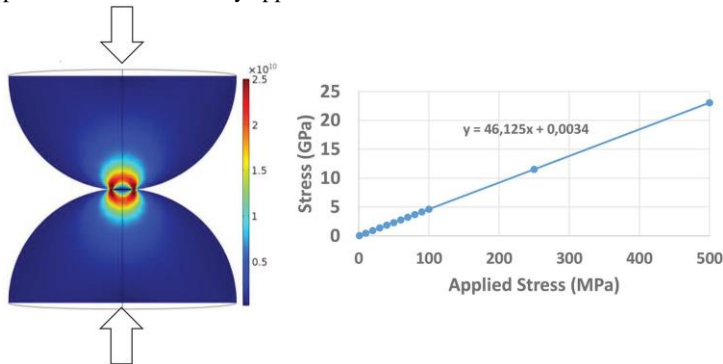
Grain size and processing effects on the properties were investigated at different scales through microstructural, Raman, and dielectric studies. The increase of the Curie temperature when the SPS pressure increased was unexpected and cannot be linked to an increase of grain size considering both the microstructural analysis and the concomitant decrease in permittivity. Interestingly, such a decrease in permittivity with increasing sintering pressure occurs despite the increase of the ceramic density. As a result, the evolution of the dielectric parameters fully discards any grain size effect. As a matter of fact, such an increase of the Curie temperature can be explained considering the local structure and can be correlated to the permittivity evolution. In view of the high surface ratio of the 20 nm grains, the core-shell model consisting in the coexistence of a cubic surface layer and a tetragonal grain core can be considered. [11] It can thus be assumed that in the first regime (i.e., pressure up to 400 MPa), the applied stress during sintering acts as a competitive external stress opposed to the mechanical surface stress due to size effect acting as an hydrostatic pressure. [39] To support this assumption and to show the link between external stress and stress at the grain scale, stress modeling was carried out at the vicinity of the contact point between two barium titanate half-spheres of 20 nm in diameter. The stress was evaluated as a function of the stress applied on the equatorial surfaces (Figure 7). The Von Mises equivalent stress was calculated by finite element modeling using Comsol Multiphysics. The used mechanical properties were those of bulk BaTiO<sub>3</sub> (Young modulus 67 GPa and Poisson coefficient 0.5). An interpenetration of 0.1 nm of the two half spheres was envisaged to ensure good contact between them and a refined mesh was used at the vicinity of the contact point. The stress values reported in Figure 7 correspond to average values of three points taken at the vicinity of the contact point. The results show that when applying an external load of 500 MPa on 20 nm grains, the resulting stress at the contact point reaches 20 GPa. Even taking into account a “dilution effect” due to the polycrystallinity of the material, the pressure at the grain scale is high enough to compete with the surface stress arising from nanometer grain size. The lateral stress was also evaluated considering as limit conditions the prescribed displacement (in the *x*-, *y*-, and *z*-axes) of the equatorial external points of the sphere. The obtained value is much lower, i.e., 130 MPa. As a result, the paraelectric shell contribution is decreased by the external applied pressure, thus leading to an increase of  $T_c$ . The internal lateral strain remains and forces the polarization along the direction of the applied pressure, which is also the direction of the applied electric field. The decrease of the permittivity is consistent with an increase of the lattice distortion, similar to what happens in Pb-doped barium titanate. [40] At pressure values higher than 400 MPa, the plateau could reflect a balance reached between the external stress and the internal surface stress and a further increase of the pressure does not affect anymore both the permittivity and  $T_c$  values. This model is supported by the Raman measurements, which show a shift of the 730 cm<sup>-1</sup> mode to higher wavenumber only up to 400 MPa. This blueshift occurs in a breathing-type mode, which is particularly sensitive to isostatic pressure. It reflects a higher lattice distortion due to strain increase in the ceramic and is in good agreement with both an increase of the Curie temperature and a decrease of the permittivity. The core-shell configuration in 20 nm grain size particles could also be described in terms of elasticity and plastic deformation regime. A maximum of bulk

modulus at a specific size of 15 nm was reported in TiO<sub>2</sub> nanoparticles.

[41] The stabilization of the dielectric parameters when increasing the pressure beyond 400 MPa should be discussed in regard to a limit of elasticity reached at a pressure threshold. Deeper investigations to probe nanoscale structural defects such as dislocations are required in order to link the lattice strain on the surface of the nanoparticles with their mechanical behavior.

The ferroelectric domain configuration is also affected in such ultrafine ferroelectric grains. [11,42] This can be seen through the softening of the maximum of losses, occurring in the vicinity of the transition temperature in bulk BST (Figure 5 c).

Grains of 20 nm size are not able to develop 90° ferroelastic-ferroelectric domains required to minimize the elastic energy resulting from the deformation of the unit cell at  $T_c$ . As a result, the domain walls present within the grains are those contributing only to polarization (180° domains). Considering the very small size of the grains, this contribution is expected to be lower than in micrometer grain size ceramics, thus minimizing losses. This aspect suggests that a judicious grain size (and thus domain) engineering could lead to fine tuning or minimization of losses which can be of considerable practical interest in many applications.



**Figure 7.** Stress at the vicinity of the contact point between two barium titanate half-spheres of 20 nm in diameter as a function of the stress applied on their equatorial surfaces, evaluated by finite element modeling.

To summarize, the main effect of SPS performed under high pressure is to increase the mismatch strain existing between the inner core and the surface of the grains (closer contact between grains in ceramics compared to the powder and high external pressure applied during sintering). The contributions of both internal and external stress effects in the nanostructured ceramics with 20 nm grain size lead to a short range dominated structure with a higher lattice distortion than in the initial powder.

After the thermal treatment at 1100 °C and whatever the pressure initially applied during SPS, the grain size within the ceramic reaches 100 nm as shown by HRSEM (Figure 3). It is expected that through this grain growth any strain present in the samples produced by SPS would be released. Interestingly, the  $T_c$  of the annealed ceramics merges in the same value (265 K) confirming that the change of  $T_c$  observed in

the 20 nm grain size ceramics is directly related to the external stress induced by the SPS pressure. Hence, the pressure applied during SPS can affect the structural distortion below a critical grain size corresponding to a surface strain high enough to be sensitive to such an additional external stress. When the surface strain is relaxed through the grain growth, the applied external pressure has no more impact on the Curie temperature. The Raman investigation also evidences a change of the local structure after annealing. The observed shift of the mode at 500–600  $\text{cm}^{-1}$  reflects an evolution towards a long range order (pseudo cubic structure). In addition, the peak at 180  $\text{cm}^{-1}$  related to size effect disappears. At 100 nm grain size, the strain arising from the surface effect is no more predominant. The remaining of some intrinsic residual strain cannot be discarded; however, the corresponding effects occur only at the very local scale and are not distinguishable in the observed Raman spectra.

#### 4. Conclusion

Advanced synthesis of ferroelectric nanoparticles and their high-pressure densification by SPS under air led to a consistent evaluation of their macroscopic and local structure.

The first outcome is that ferroelectricity is preserved in dense ceramics of 20 nm grain size while the transition temperature decreased. We achieved an improved control of the dielectric permittivity and losses which were not altered by spurious defects and grain boundaries. This enabled a reliable evaluation of the external stress effect on the transition temperature. Increasing the uniaxial pressure during the sintering step up to several hundreds of MPa, we were able to break the paraelectric shell, impacting the ferroelectric core of each individual grain, and thus restoring ferroelectricity through an increase of the transition temperature. This was ascribed to the hardening of the oxygen octahedra breathing mode which is primarily sensitive to the strain at the unit cell level. Our conclusions were supported by finite element modeling simulations which highlight the very high stress generated at the grain scale. These results open new insights to explore the pressure effect during SPS sintering on the intrinsic properties of polycrystalline nanomaterials when focusing on a grain size regime small enough to become particularly sensitive to an external stress.

#### 5. Experimental Section

The starting chemicals used were barium isopropoxide (99.9%, Aldrich, CAS: 24363-37-9), strontium isopropoxide (99.9%, Aldrich, CAS: 88863-33-6), titanium isopropoxide ( $\epsilon$ 98%, Strem chemicals, CAS: 546-68-9), and ethanol ( $\epsilon$ 99.8%, Aldrich, CAS: 64-17-5). The entire BST solid solution can be processed using supercritical fluids technology simply by adjusting the precursor ratio to the expected composition prior injection of the mixture in the reactor. [24,25] The tubular reactor used in the setup had an overall length of 24 m in which the residence time was set to 50 s. The temperature and the pressure within the reactor were 400 °C and 23 MPa, respectively. The molar fraction of ethanol in water was set at 0.29, leading to a mixture with a supercritical point at  $T_c = 305$  °C and  $P_c = 17$  MPa, which are lower than the ones of pure water ( $T_c = 374$  °C and  $P_c = 22.1$  MPa). The solvent ratio (ethanol/water) is a key parameter to improve the crystallinity of the nanoparticles. Spark plasma sintering was performed using a Dr Sinter 2080 SPS device (SPS Syntex Inc., Tokyo Japan) of the Plateforme Nationale CNRS de Frittage Flash located at Université Toulouse Paul Sabatier III. BST powder (without any sintering aids) was loaded onto an 8 mm inner diameter cylindrical tungsten carbide die covered with a graphite foil. The sintering was performed under air at 750 °C, holding time 2 min, pulse sequence 12–2 (on–off), and an uniaxial pressure in the range of 300 MPa up to 600 MPa was applied. Considering the high surface reactivity of the nanopowders,

the pressure was applied at the beginning of the cycle at room temperature in order to avoid grain growth. The pressure was then gradually removed before cooling to minimize strain within the sample. An annealing under air at a temperature lower than the sintering temperature (700 °C during 10 h) was performed in order to release residual stress arising from SPS process and also to remove any contribution of conductivity which can occur due to surface contamination resulting from the use of the carbon foil and from the strong reactivity of the nanoparticles.

In order to induce grain growth, a post thermal annealing treatment was performed in air at 1100 °C during 10 h.

Diffraction patterns were recorded at room temperature with a PANalytical X'Pert MPD-PRO powder diffractometer equipped with a germanium monochromator. The diffraction of the Cu K $\alpha$  radiation at  $\lambda = 1.54060 \text{ \AA}$  generated at 45 kV and 40 mA is only observed.

TEM was performed using a JEOL 2200FS with an accelerating voltage of 200 kV and equipped with a high resolution camera. The resolution is 0.23 nm. The Digital Micrograph (GATAN) software was used to record the pictures. HRSEM maps were obtained using a scanning electron microscope (SEM) JEOL JSM 7800F Prime, at the Unité Mixte de Service (UMS) Raymond Castaing, Toulouse. The smallest grains (<10 nm) were evidenced by using a low acceleration voltage (2 kV) and without any metallization of the sample.

The Raman spectrometer used was a Thermo Scientific DXR microscope with a 532 nm wavelength excitation laser operating at 8 mW output power. Focusing was realized with a confocal microscope equipped with a 10 $\times$  objective, leading to a surface analysis area of 3.5  $\mu\text{m}^2$ . The resolution was 3  $\text{cm}^{-1}$  over a window from 15 to 3550  $\text{cm}^{-1}$ . The dielectric measurements were carried out with an automatic Wayne–Kerr 6425 impedance bench developed at ICMCB in a frequency range from 100 Hz to 200 kHz. Gold electrodes were deposited on two parallel faces of the ceramic and the real and imaginary contributions of the permittivity,  $\Sigma_2$  and  $\Sigma_3$ , were respectively determined from the measured capacitance ( $C$ ) and losses ( $\tan \delta$ ).

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